



BC846A-BC848C

NPN SMALL SIGNAL TRANSISTOR IN SOT23

#### Features

- Ideally Suited for Automatic Insertion
- Complementary PNP Types: BC856 BC858
- For switching and AF Amplifier Applications
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

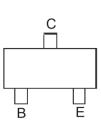
#### **Mechanical Data**

- Case: SOT23
- Case material: molded plastic, "Green" molding compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.008 grams (Approximate)



Top View

**Device Symbol** 



Top View Pin-Out

# Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Quantity per reel
BC846A-7-F	AEC-Q101	K1Q	7	3,000
BC846AQ-7-F	Automotive	K1Q	7	3,000
BC846B-7-F	AEC-Q101	K1R	7	3,000
BC846BQ-7-F	Automotive	K1R	7	3,000
BC846B-13-F	AEC-Q101	K1R	13	10,000
BC846BQ-13-F	Automotive	K1R	13	10,000
BC847A-7-F	AEC-Q101	K1Q	7	3,000
BC847AQ-7-F	Automotive	K1Q	7	3,000
BC847A-13-F	AEC-Q101	K1Q	13	10,000
BC847B-7-F	AEC-Q101	K1R	7	3,000
BC847BQ-7-F	Automotive	K1R	7	3,000

Product	Compliance	Marking	Reel size (inches)	Quantity per reel
BC847B-13-F	AEC-Q101	K1R	13	10,000
BC847C-7-F	AEC-Q101	K1M	7	3,000
BC847CQ-7-F	Automotive	K1M	7	3,000
BC847C-13-F	AEC-Q101	K1M	13	10,000
BC848A-7-F	AEC-Q101	K1Q	7	3,000
BC848B-7-F	AEC-Q101	K1R	7	3,000
BC848B-13-F	AEC-Q101	K1R	13	10,000
BC848C-7-F	AEC-Q101	K1M	7	3,000
BC848CQ-7-F	Automotive	K1M	7	3,000

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

 See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.

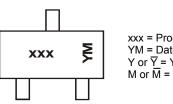
3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

A Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally

the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product\_compliance\_definitions/.

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

### **Marking Information**



xxx = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: Y = 2011)

M or  $\overline{M}$  = Month (ex: 9 = September)

Date Code Key												
Year	2010		2011	2012		2013	2014		2015	2016		2017
Code	Х		Y	Z		А	В		С	D		E
Mausth	lan	Fab	Man	<b>A</b>	Mari	1	11	Aug	Sep	Oct	Nov	Dec
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Seh	001		Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D



#### Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Character	istic	Symbol	Value	Unit
	BC846		80	
Collector-Base Voltage	BC847	V <sub>CBO</sub>	50	V
	BC848		30	
	BC846		65	
Collector-Emitter Voltage	BC847	V <sub>CEO</sub>	45	V
	BC848		30	
Emitter Base Voltage	BC846, BC847	M	6.0	M
Emitter-Base Voltage	BC848	V <sub>EBO</sub>	5.0	v
Continuous Collector Current		lc	100	mA
Peak Collector Current		I <sub>CM</sub>	200	mA
Peak Emitter Current		I <sub>EM</sub>	200	mA

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Rower Dissinction	(Note 6)	Р	310	mW	
Power Dissipation	(Note 7)	P <sub>D</sub>	350	IIIVV	
Thermal Decistance, Junction to Ambient	(Note 6)	D	403	0000	
Thermal Resistance, Junction to Ambient	(Note 7)	R <sub>0JA</sub>	357	°C/W	
Thermal Resistance, Junction to Leads (Note 8)		R <sub>θJL</sub>	350	°C/W	
Operating and Storage Temperature Range	·	T <sub>J</sub> ,T <sub>STG</sub>	-65 to +150	۵°	

#### ESD Ratings (Note 9)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes:

For a device mounted on minimum recommended pad layout 1oz copper that is on a single-sided FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.

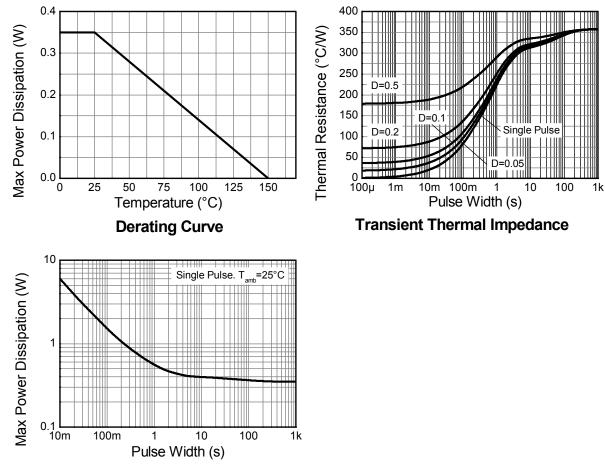
7. Same as note (6), except the device is mounted on 15 mm x 15mm 1oz copper.

8. Thermal resistance from junction to solder-point (at the end of the leads).

9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



#### **Thermal Characteristics and Derating Information**



Pulse Power Dissipation



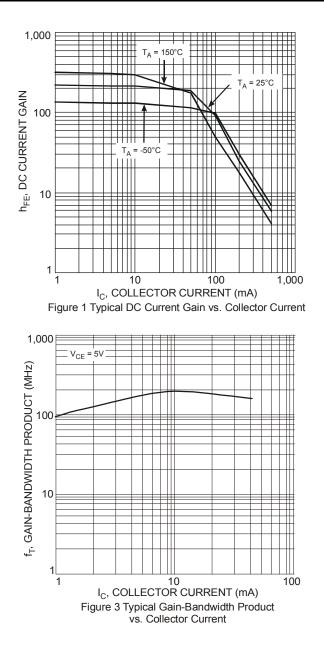
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

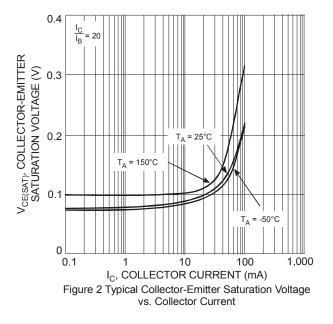
Ch	aracteristic		Symbol	Min	Тур	Max	Unit	Test Condition	
		BC846		80					
Collector-Base Breakdown Voltage		BC847	<b>BV</b> CBO	50	—	_	V	I <sub>C</sub> = 10μA	
		BC848		30					
Collector Emitter Breakdown	Voltago	BC846		65		_			
Collector-Emitter Breakdown (Note 10)	vollage	BC847	BV <sub>CEO</sub>	45	—		V	I <sub>C</sub> = 10mA	
(Note 10)		BC848		30					
Emitter-Base Breakdown Vol	Itago	BC846 / BC847	BVEBO	6			V	I <sub>E</sub> = 1μΑ	
Emilier-Base Breakdown vo	llaye	BC848	DVEBO	5	_		v	IE – TμA	
Collector Cutoff Current			I <sub>CBO</sub>		_	15	nA	V <sub>CB</sub> = 30V	
			ICBO			5	μA	V <sub>CB</sub> = 30V, T <sub>J</sub> = +150°C	
		BC846				15		V <sub>CE</sub> = 80V	
Collector Emitter Cutoff Curre	ent	BC847	ICES	_	—	15	nA	V <sub>CE</sub> = 50V	
		BC848				15		V <sub>CE</sub> = 30V	
Emitter Base Cutoff Current			I <sub>EBO</sub>	_	_	100	nA	V <sub>EB</sub> = 5V	
Creall Cianal Current Cain	BC846A / E	3C847A / BC848A			200				
Small Signal Current Gain (Note 10)		BC846B / BC847B / BC848B			330				
	BC84	7C / BC848C	h <sub>fe</sub>		600				
Input Impedance		3C847A / BC848A			2.7				
(Note 10)	BC846B / BC847B / BC848B		h <sub>ie</sub>	—	4.5	—	kΩ		
(Note 10)	BC847C / BC848C				8.7			I <sub>C</sub> = 2.0mA, V <sub>CE</sub> = 5V	
Output Admittance		BC846A / BC847A / BC848A		h <sub>oe</sub> —	18		μS	f=1.0kHz	
(Note 10)	BC846B / BC847B / BC848B		h <sub>oe</sub>		30				
		7C / BC848C			60			-	
Reverse Voltage Transfer		3C847A / BC848A		_	1.5x10 <sup>-4</sup>	_	_		
Ratio (Note 10)		3C847B / BC848B	h <sub>re</sub>		2x10 <sup>-4</sup>				
		7C / BC848C			3x10⁻⁴				
		3C847A / BC848A		110	180	220			
DC Current Gain (Note 10)		3C847B / BC848B	h <sub>FE</sub>	200	290	450	—	$I_{C} = 2.0 \text{mA}, V_{CE} = 5 \text{V}$	
		7C / BC848C		420	520	800			
Collector-Emitter Saturation	Voltage		V <sub>CE(sat)</sub>	_	90	250	mV	$I_{\rm C}$ = 10mA, $I_{\rm B}$ = 0.5mA	
(Note 10)			• CE(sat)		200	600		I <sub>C</sub> = 100mA, I <sub>B</sub> = 5.0mA	
Base-Emitter Turn-On Voltag	ne(Note 10)		V <sub>BE(on)</sub>	580	660	700	mV	$I_{C} = 2mA, V_{CE} = 5V$	
			V BE(OD)	_	—	770	111 V	I <sub>C</sub> = 10mA, V <sub>CE</sub> = 5V	
Base-Emitter Saturation Volt	ago(Nioto 10)		<b>M</b> =		700		mV	I <sub>C</sub> = 10mA, I <sub>B</sub> = 0.5mA	
Base-Emilier Saturation Volt	age(Note 10)		V <sub>BE(sat)</sub>	_	900	—	IIIV	I <sub>C</sub> = 100mA, I <sub>B</sub> = 5mA	
Output Capacitance			Cobo	_	3	—	pF	V <sub>CB</sub> = 10V, f = 1.0MHz	
Transition Frequency			f <sub>T</sub>	100	300	_	MHz	V <sub>CE</sub> = 5V, I <sub>C</sub> = 10mA, f = 100MHz	
Noise Figure			NF	_	2	10	dB	V <sub>CE</sub> =5V, I <sub>C</sub> =200μA R <sub>S</sub> =2kΩ, f=1kHz Δf=200Hz	

Note: 10. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%



# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

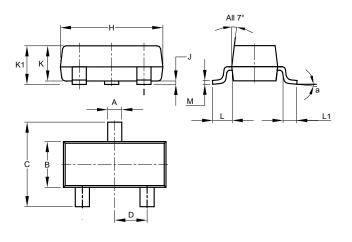






### **Package Outline Dimensions**

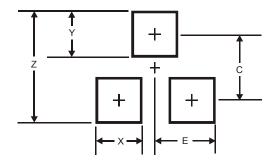
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



	SOT23								
Dim	Min	Min Max Typ							
Α	0.37	0.51	0.40						
В	1.20	1.40	1.30						
С	2.30	2.50	2.40						
D	0.89	1.03	0.915						
F	0.45	0.60	0.535						
G	1.78	2.05	1.83						
н	2.80	3.00	2.90						
J	0.013	0.10	0.05						
К	0.890	1.00	0.975						
K1	0.903	1.10	1.025						
L	0.45	0.61	0.55						
L1	0.25	0.55	0.40						
М	0.085	0.150	0.110						
а	8°								
All	Dimens	ions in	mm						

# Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35



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